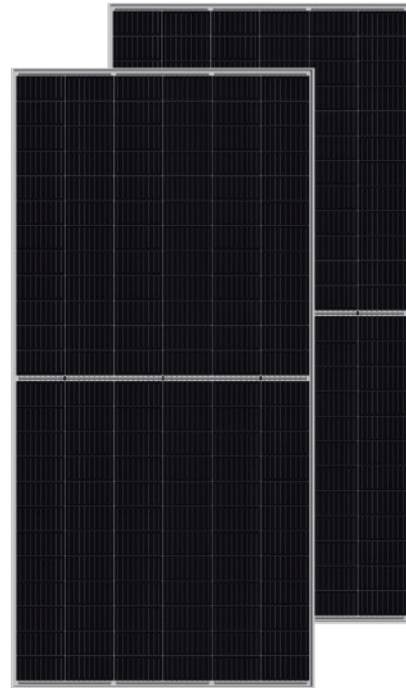


BISTAR

TP6F72M
TP6F72M(H) **144 half-cell**

390 - 410W

9BB half-cut mono perc



KEY FEATURES



9BB half-cut cell technology

New circuit design, lower internal current, lower Rs loss



Significantly lower the risk of hot spot

Special circuit design with much lower hot spot temperature



Lower LCOE

2% more power generation, lower LCOE



Anti
PID

Excellent Anti-PID performance

2 times of industry standard Anti-PID test by TUV SUD



IP68 junction box

High waterproof level

SYSTEM & PRODUCT CERTIFICATES

- IEC 61215 / IEC 61730 / UL 1703
- ISO 9001: 2015 Quality Management System
- ISO 14001: 2015 Environment Management System
- ISO 45001: 2018 Occupational Health and Safety Management Systems

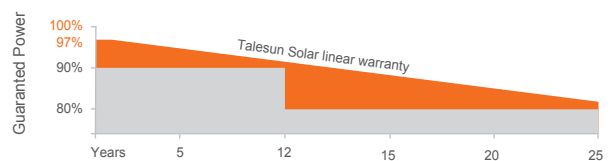


PERFORMANCE WARRANTY

12 years
Quality assurance

25 years
Power output guarantee

■ Talesun standard
■ Industry standard



ELECTRICAL PARAMETERS

Performance at STC (Power Tolerance 0 ~ +3%)

Maximum Power (Pmax/W)	390	395	400	405	410
Operating Voltage (Vmpp/V)	40.0	40.3	40.5	40.7	40.9
Operating Current (Impp/A)	9.75	9.81	9.89	9.96	10.04
Open-Circuit Voltage (Voc/V)	48.7	48.9	49.1	49.3	49.5
Short-Circuit Current (Isc/A)	10.28	10.35	10.43	10.50	10.58
Module Efficiency η m(%)	19.4	19.6	19.9	20.1	20.4

Performance at NMOT

Maximum Power (Pmax/W)	290.8	294.6	298.5	302.1	305.9
Operating Voltage (Vmpp/V)	37.3	37.5	37.7	37.9	38.0
Operating Current (Impp/A)	7.80	7.85	7.93	7.98	8.04
Open-Circuit Voltage (Voc/V)	45.4	45.5	45.7	45.9	46.1
Short-Circuit Current (Isc/A)	8.30	8.35	8.42	8.48	8.54

STC: Irradiance 1000W/m², Cell Temperature 25°C, Air Mass AM1.5 NMOT: Irradiance at 800W/m², Ambient Temperature 20°C, Air Mass AM1.5, Wind Speed 1m/s

MECHANICAL SPECIFICATION

Cell Type	Mono-Crystalline Silicon (9Busbar)
Cell Dimensions	158.75*158.75mm (6inches)
Cell Arrangement	144 (6*24)
Weight	22.5kg (49.6lbs)
Module Dimensions	2008*1002*35mm (79.06*39.45*1.38inches)
Cable Length	300mm (11.81inches)
Cable Cross Section Size	4mm ² (0.006inches ²)
Front Glass	3.2mm High Transmission, Tempered Glass
No. of Bypass Diodes	3/6
Packing Configuration(1)	30pcs/carton, 660pcs/40hq
Packing Configuration(2)	30+4pcs/carton, 704pcs/40hq
Frame	Anodized Aluminium Alloy
Junction Box	IP68

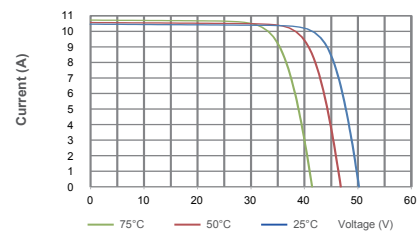
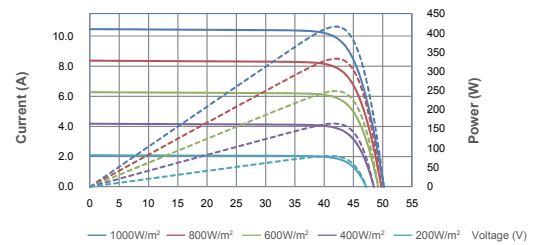
OPERATING CONDITIONS

Maximum System Voltage	1000V/1500V/DC(IEC)
Operating Temperature	-40°C ~ +85°C
Maximum Series Fuse	20A
Static Loading	5400pa
Conductivity at Ground	≤0.1Ω
Safety Class	II
Resistance	≥100MΩ
Connector	MC4 Compatible

TEMPERATURE COEFFICIENT

Temperature Coefficient Pmax	-0.39%/°C
Temperature Coefficient Voc	-0.30%/°C
Temperature Coefficient Isc	+0.05%/°C
NMOT	43±2°C

I-V CURVE



TECHNICAL DRAWINGS

